



Product Summary

BV _{DSS}	Max R _{DS(ON)}	Max I _D T _A = +25°C
20V	0.1Ω @ V _{GS} = 4.5V	3.2A
	0.125Ω @ V _{GS} = 2.7V	2.8A

Description and Applications

This high-density MOSFET from Diodes Incorporated utilizes a unique structure that combines the benefits of low, on-resistance with fast switching speed. This makes it ideal for high-efficiency, low voltage power management applications such as:

- DC-DC Converters
- Power Management Functions
- Disconnect Switches
- Motor Control

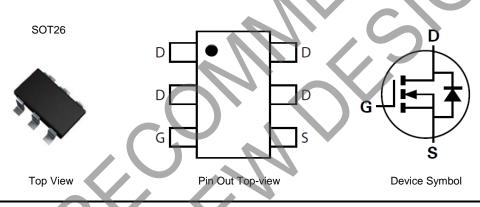
20V N-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Low On-Resistance
- Fast Switching Speed
- Low Threshold
- Low Gate Drive
- SOT26 Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 3
- Weight: 0.015 grams (Approximate)



Ordering Information (Note 4)

	Part Number	Reel Size (inch)	Tape Width (mm)	Quantity Per Reel
	ZXM62N02E6TA	7	8	3,000
	ZXM62N02E6TC	13	8	10,000
Notes: 1. No purposely added lead, Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.				

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information SOT26 2N02 = Product Type Marking Code YM = Date Code Marking Σ 2N02 Y or \overline{Y} = Year (ex: F = 2018) M or \overline{M} = Month (ex: 9 = September) Date Code Key Year 2015 2016 2017 2018 2019 2020 2021 Code С D F F G н Month Mar Jan Feb Apr May Jun Jul Aug Sep Oct

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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit	
Drain-Source Voltage			V _{DSS}	20	V	
Gate-Source Voltage			V _{GS}	±12	V	
Continuous Drain Current		(Note 6)	Ι _D	3.2	А	
	V _{GS} = 4.5V	T _A = +70°C (Note 6)		2.6		
Pulsed Drain Current (Note 7)		(Note 7)	I _{DM}	18	А	
Continuous Source Current (Body Diode) (Note 6)		Is	2.1	А		
Pulsed Source Current (Body Diode)			Ism	18	А	

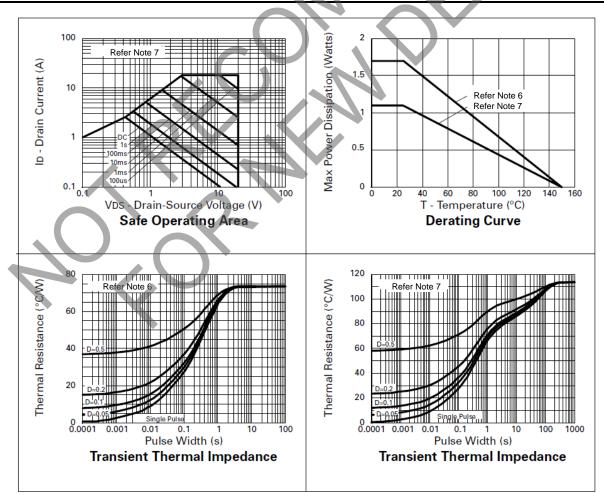
Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation (Note 5) Linear Derating Factor		PD	1.1 8.8	W mW/°C
Power Dissipation (Note 6) Linear Derating Factor		P _D 1.7 13.6		W mW/°C
Thermal Resistance, Junction to Ambient	(Note 5) (Note 6)	– R _θ JA	113 73	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

Notes: 5. For a device surface mounted on 25mm x 25mm FR-4 PCB with high coverage of single sided 1oz copper, in still air conditions. 6. For a device surface mounted on FR-4 PCB measured at t ≤ 5 seconds.

7. Repetitive rating - pulse width limited by maximum junction temperature. Refer to Transient Thermal Impedance graph.

Thermal Characteristics





Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	20			V	$I_D = 250 \mu A, V_{GS} = 0 V$
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μA	$V_{DS} = 20V, V_{GS} = 0V$
Gate-Body Leakage	I _{GSS}	_	_	100	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$
ON CHARACTERISTICS						
Gate-Source Threshold Voltage	V _{GS(TH)}	0.7	_	_	V	$I_D = 250\mu A$, $V_{DS} = V_{GS}$
Static Drain-Source On-Resistance (Note 8)	Desser			0.1	Ω	$V_{GS} = 4.5V, I_D = 2.2A$
	R _{DS(ON)}	_	_	0.125	12	V _{GS} = 2.7V, I _D = 1.1A
Forward Transconductance	g fs	3.2	_	_	S	V _{DS} = 10V, I _D = 1.1A
Diode Forward Voltage (Note 8)	V _{SD}	_	_	0.95	V	T_{J} = +25°C, I_{S} = 2.2A, V_{GS} = 0V
DYNAMIC CHARACTERISTICS (Note 10)						
Input Capacitance	Ciss		460	_	pF	
Output Capacitance	Coss		150	_	рF	V _{DS} = 15V, V _{GS} = 0V f = 1MHz
Reverse Transfer Capacitance	Crss	_	50	1	pF	
Total Gate Charge (Note 9)	Qg	_	—	6.3	nC	$V_{DS} = 16V, V_{GS} = 4.5V,$
Gate-Source Charge (Note 9)	Q _{gs}	_	_	1.5	nC	$I_D = 2.2A$ (refer to
Gate-Drain Charge (Note 9)	Q _{gd}	_		2.5	nC	test circuit)
Turn-On Delay Time (Note 9)	t _{d(on)}		4.0		ns	
Turn-On Rise Time (Note 9)	tr	-	10.4	_	ns	$V_{DD} = 10V, I_D = 2.2A,$
Turn-Off Delay Time (Note 9)	t _{d(off)}	4	16.9	-	ns	$R_G = 6.0\Omega$, $R_D = 4.4\Omega$ (refer to test circuit)
Turn-Off Fall Time (Note 9)	t _f		8.0		ns	
Reverse Recovery Time	trr		17.5		ns	T _J = +25°C, I _F = 2.2A,
Reverse Recovery Charge	Qrr		8.6	-	nC	di/dt = 100A/µs

8. Measured under pulsed conditions. Width \leq 300µs. Duty cycle \leq 2%. 9. Switching characteristics are independent of operating junction temperature. 10. For design aid only, not subject to production testing. Notes:

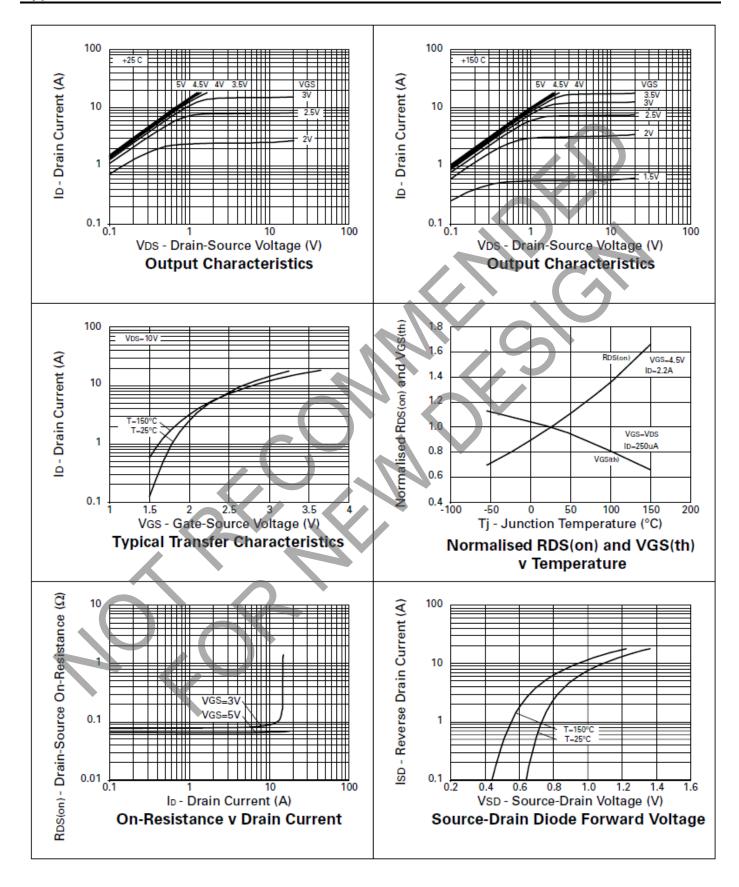




NOT RECOMMENDED FOR NEW DESIGN -NO ALTERNATE PART

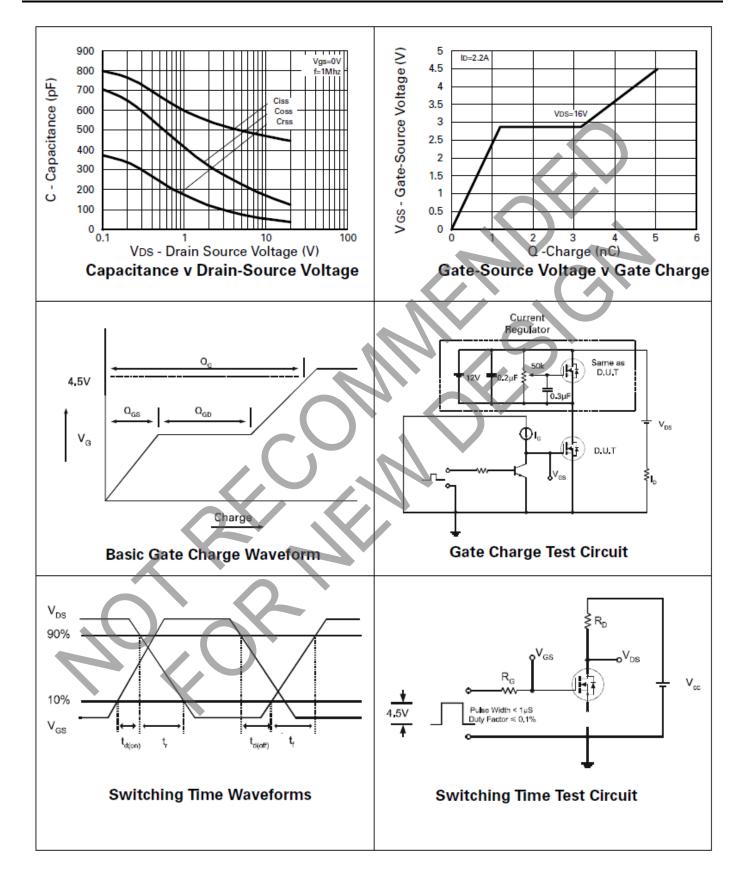
ZXM62N02E6

Typical Characteristics





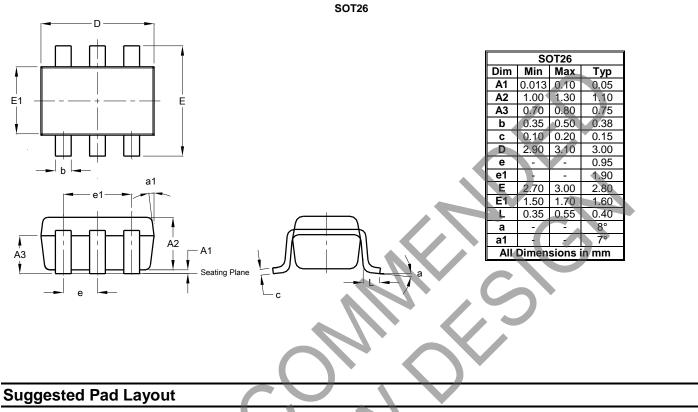
Typical Characteristics (cont.)



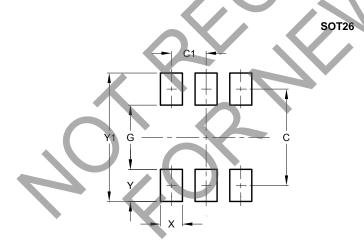


Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



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Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
Х	0.55
Y	0.80
Y1	3.20



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